

## HIGH SPEED POWER DRIVER

Check for Samples: UC1705, UC2705, UC3705

### FEATURES

- 1.5 A Source/Sink Drive
- 100 nsec Delay
- 40 nsec Rise Fall into 1000 pF
- Inverting and Non-Inverting Inputs
- Low Cross-Conduction Current Spike

### nuto

### DESCRIPTION

- Low Quiescent Current
  5 V to 40 V Operation
- Thermal Shutdown Protection
- Minidip and Power Packages

The UC1705 family of power drivers is made with a high sppeed Schottky process to interface between low-level control functions and high-power switching devices - particularly power MOSFETs. These devices are also an optimum choise for capacitive line drivers where up to 1.5 A may be switched in either direction. With both inverting and non-inverting inputs available, logic signals of either polarity may be accepted, or one input can be used to gate or strobe the other.

Supply voltages for both  $V_S$  and  $V_C$  can independently range from 5 V to 40 V. For additional application details, see the UC1707/3707 data sheet (SLUS177).

The UC1705 is packaged in an 8-pin hermetically sealed CERDIP for -55°C to 125°C operation. The UC3705 is specified for a temperature range of 0°C to 70°C and is available in either a plastic minidip or a 5-pin, power TO-220 package.

### TRUTH TABLE<sup>(1)(2)</sup>

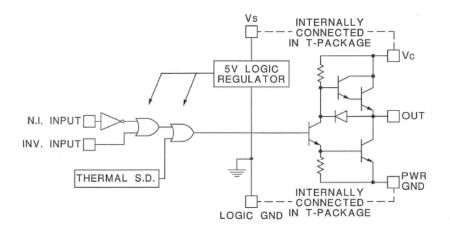
INV	N.I	OUT
Н	Н	L
L	Н	Н
Н	L	L
L	L	L

(1)  $\underline{OUT} = \overline{INV}$  and N.I.

(2)  $\overline{OUT} = INV \text{ and } N.i.$ 

### **BLOCK DIAGRAM**

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## UC1705 UC2705, UC3705

SLUS370D-JULY 1995-REVISED MARCH 2012

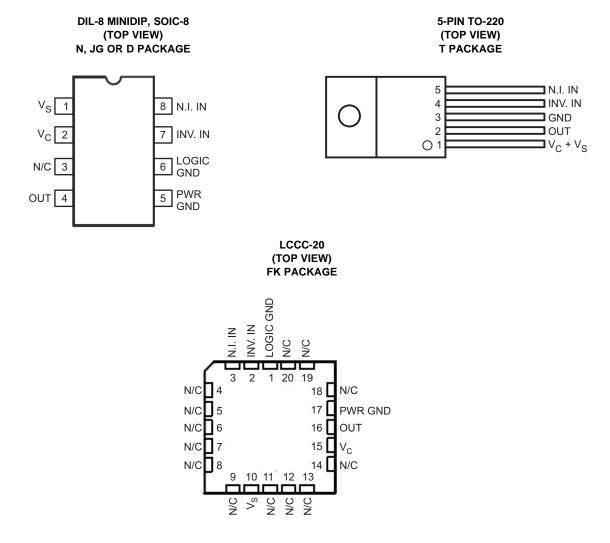


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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### **CONNECTION DIAGRAMS**



### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

		VALUE		UNIT	
	N-Pkg	JG-Pkg	T-Pkg	UNIT	
Supply Voltage (V <sub>IN</sub> )	40	40	40	V	
Collector Supply Voltage, V <sub>C</sub>	40	40	40		
Output current (source or sink)					
Steady-State	±500	±500	±1	А	
Peak Transient	±1.5	±1	±2	А	
Capacitive Discharge Energy	20	15	50	μJ	
Digital Inputs <sup>(2)</sup>	5.5	5.5	5.5	V	
Power Dissipation at $T_A = 25^{\circ}C^{(1)}$	1	1	3	W	
Power Dissipation at $T_A$ (Lead/Case) = 25°C <sup>(1)</sup>	3	2	25	W	
Operating Temperature Range	0 to 70	-55 to 125	0 to 70	°C	
Storage temperaturee	-65 to 150	-65 to 150	-65 to 150	°C	

(1) All currents are positive into, negative out of the specified terminal.

(2) Digital Drive can exceed 5.5 V if the input current is limited to 10 mA

## **ELECTRICAL CHARACTERISTICS**

Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}C$  to  $+125^{\circ}C$  for the UC1705,  $-25^{\circ}C$  to  $+85^{\circ}C$  for the UC2707, and 0°C to  $+70^{\circ}C$  for the UC3705;  $V_{IN} = V_C = 20$  V.  $T_A = T_J$ .

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V	Current current	V <sub>S</sub> = 40 V, outputs high, T package		6	8	mA
VS	Supply current	$V_{C}$ = 40 V, outputs low, T package		6	12	mA
V <sub>C</sub>	Supply current (N, JG Only)	$V_{\rm C}$ = 40 V, outputs low		2	4	mA
V <sub>C</sub>	Leakage current (N, JG Only)	$V_{\rm S} = 0, V_{\rm C} = 30 \ {\rm V}$		0.05	0.1	mA
	Digital input low level				0.8	V
	Digital input high level		2.2			V
	Input current	V <sub>1</sub> = 0		-0.6	-1	mA
	Input leakage	V <sub>I</sub> = 5 V		0.05	0.1	mA
V V	Output high acturation	I <sub>O</sub> = -50 mA			2	V
vc - vo	$V_{C} - V_{O}$ Output high saturation	I <sub>O</sub> = -500 mA			2.5	v
V		I <sub>O</sub> = -50 mA			0.4	
Vo	Output low saturation	I <sub>O</sub> = -500 mA			2.5	V
	Thermal shutdown			155		°C

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### **TYPICAL SWITCHING CHARACTERISTICS**

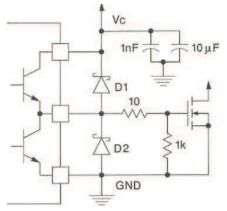
 $V_{IN} = V_C = 20 \text{ V}, \text{ }T_A = 25^{\circ}\text{C}. \text{ Delays measured to } 10\% \text{ output change.}$ 

PARAMETER	TEST CONDITIONS	OUTI	OUTPUT CL =			
From Inv. Input to Output	·	open	1	2.2	nF	
Rise time delay		60	60	60	ns	
10% to 90% rise		20	40	60	ns	
Fall time delay		60	60	60	ns	
90% to 10% fall		25	40	50	ns	
From N.I. Input to Output						
Rise time delay		90	90	90	ns	
10% to 90% rise		20	40	60	ns	
Fall time delay		60	60	60	ns	
90% to 10% fall		25	40	50	ns	
V <sub>C</sub> cross-conduction current spike duration	Output rise	25			ns	
	Output fall	0			ns	

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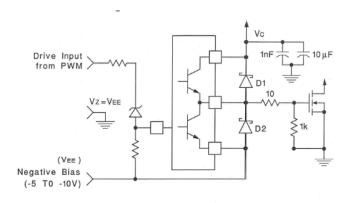


### **APPLICATION INFORMATION**



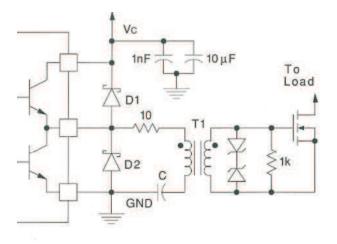
D1, D2: UC3611 Schottky Diodes

Figure 1. Power MOSFET Drive Circuit



D1, D2: UC3611 Schottky Diodes

#### Figure 2. Power MOSFET Drive Circuit Using Negative Bias Voltage and Level Shifting to Ground Referenced PWMs



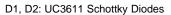


Figure 3. Transformer Coupled MOSFET DRIVE Circuit

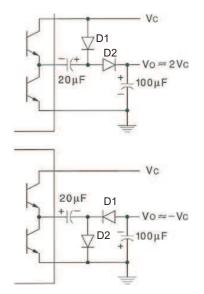


Figure 4. Charge Pump Circuit

### **REVISION HISTORY**

Cł	nanges from Revision C (December, 2011) to Revision D	Page
•	Deleted SN54BCT373 from title for FK package image	2



28-Jul-2020

## **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9579801M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9579801M2A UC1705L/ 883B	Samples
5962-9579801MPA	ACTIVE	CDIP	JG	8	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	9579801MPA UC1705	Samples
5962-9579801VPA	ACTIVE	CDIP	JG	8	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	9579801VPA UC1705	Samples
UC1705J	ACTIVE	CDIP	JG	8	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	UC1705J	Samples
UC1705J883B	ACTIVE	CDIP	JG	8	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	9579801MPA UC1705	Samples
UC1705L883B	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9579801M2A UC1705L/ 883B	Samples
UC2705D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2705D	Samples
UC2705DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2705D	Samples
UC2705N	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-40 to 85	UC2705N	Samples
UC3705D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3705D	Samples
UC3705DTR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3705D	Samples
UC3705J	ACTIVE	CDIP	JG	8	1	TBD	SNPB	N / A for Pkg Type	0 to 70	UC3705J	Samples
UC3705N	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	0 to 70	UC3705N	Samples

(1) The marketing status values are defined as follows: ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.



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**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF UC1705, UC1705-SP, UC3705, UC3705M :

- Catalog: UC3705, UC1705, UC3705M, UC3705
- Military: UC1705, UC1705
- Space: UC1705-SP

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product





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Military - QML certified for Military and Defense Applications

• Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

## PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

TEXAS INSTRUMENTS





#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

\*All dimensions are nominal

TAPE AND REEL INFORMATION

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC3705DTR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UC3705DTR	SOIC	D	8	2500	367.0	367.0	35.0

LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N\*\*) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



# D0008A



## **PACKAGE OUTLINE**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



# D0008A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## D0008A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

MCER001A - JANUARY 1995 - REVISED JANUARY 1997



#### **CERAMIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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